onsemi

Switch-mode Power Rectifier

45 V, 40 A

MBR40L45CTG, NRVBB40L45CTT4G

Features and Benefits

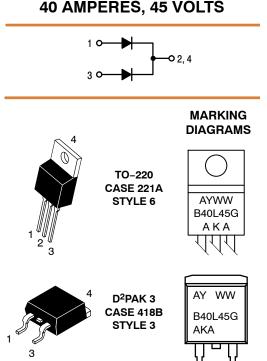
- Low Forward Voltage
- Low Power Loss/High Efficiency
- High Surge Capacity
- 175°C Operating Junction Temperature
- 40 A Total (20 A Per Diode Leg)
- Guard-Ring for Stress Protection
- NRVBB Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

Applications

- Power Supply Output Rectification
- Power Management
- Instrumentation

Mechanical Characteristics:

- Case: Epoxy, Molded
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Weight (Approximately): 1.9 Grams (TO-220)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Shipped 50 Units Per Plastic Tube for TO-220



SCHOTTKY BARRIER

RECTIFIERS

B40L45 A Y	= Device Code = Assembly Location = Year
WW	= Work Week
G	= Pb-Free Device
AKA	= Polarity Designator

ORDERING INFORMATION

Device	Package	Shipping [†]
MBR40L45CTG	TO-220 (Pb-Free)	50 Units/Rail
NRVBB40L45CTT4G	D ² PAK 3 (Pb–Free)	800 /Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

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MAXIMUM RATINGS (Per Diode Leg)

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	45	V
Average Rectified Forward Current (Rated V_R) T_C = 145°C	I _{F(AV)}	20	A
Peak Repetitive Forward Current (Rated V _R , Square Wave, 20 kHz)	I _{FRM}	40	A
Non-repetitive Peak Surge Current (Surge applied at rated load conditions half-wave, single phase, 60 Hz)	I _{FSM}	200	A
Operating Junction Temperature (Note 1)	TJ	-65 to +175	°C
Storage Temperature	T _{stg}	-65 to +175	°C
Voltage Rate of Change (Rated V _R)	dv/dt	10,000	V/μs
ESD Ratings: Machine Model = C Human Body Model = 3B		> 400 > 8000	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. The heat generated must be less than the thermal conductivity from Junction-to-Ambient: $dP_D/dT_J < 1/R_{\theta JA}$.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Maximum Thermal Resistance Junction-to-Case Junction-to-Ambient	${f R}_{ heta JC} {f R}_{ heta JA}$	1.9 72.9	°C/W

ELECTRICAL CHARACTERISTICS (Per Diode Leg)

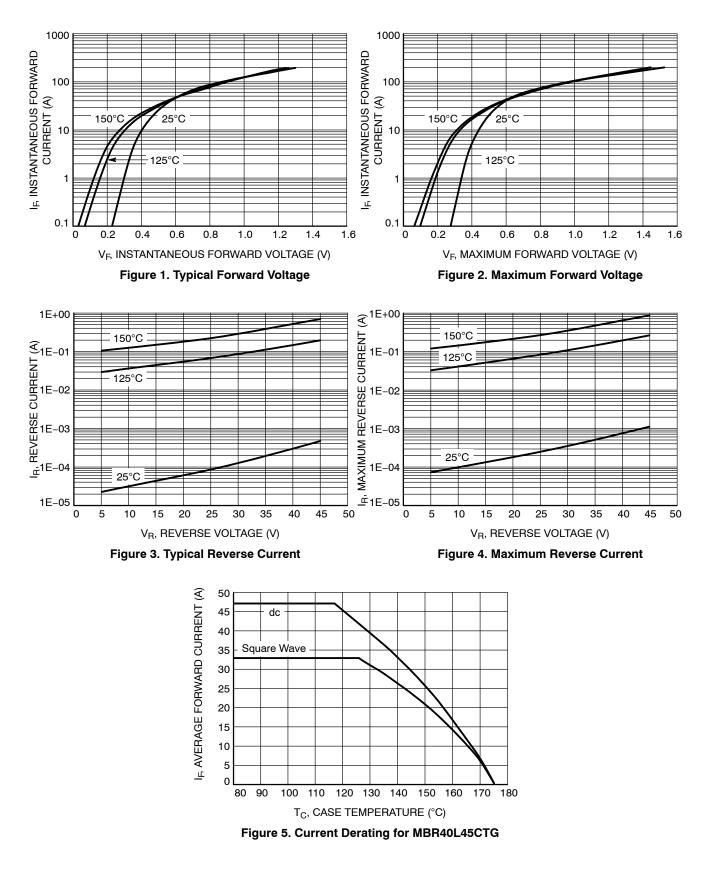
Characteristic	Symbol	Value	Unit
	VF	0.50 0.48 0.63 0.68	V
Maximum Instantaneous Reverse Current (Note 2) (Rated DC Voltage, $T_C = 25^{\circ}C$) (Rated DC Voltage, $T_C = 125^{\circ}C$)	İR	1.2 275	mA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.

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TYPICAL CHARACTERISTICS



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TYPICAL CHARACTERISTICS

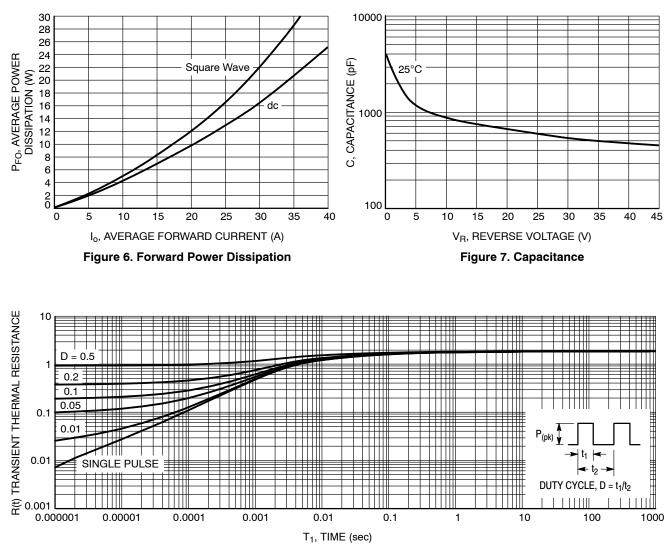
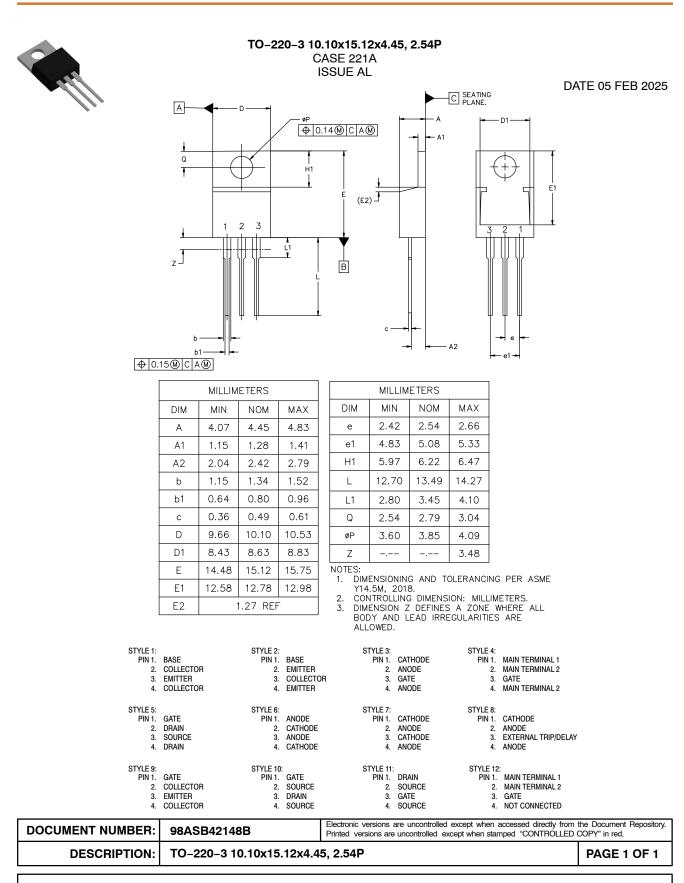


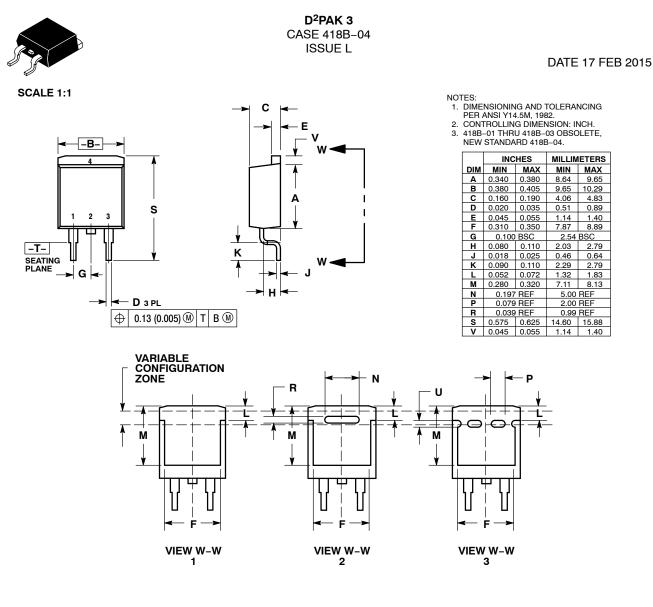
Figure 8. Thermal Response Junction-to-Case for MBR40L45CTG





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STYLE 1:	STYLE 2:	STYLE 3:	STYLE 4:	STYLE 5:	STYLE 6:
PIN 1. BASE	PIN 1. GATE	PIN 1. ANODE	PIN 1. GATE	PIN 1. CATHODE	PIN 1. NO CONNECT
2. COLLECTOR	2. DRAIN	2. CATHODE	2. COLLECTOR	2. ANODE	2. CATHODE
3. EMITTER	SOURCE	ANODE	3. EMITTER	CATHODE	3. ANODE
4. COLLECTOR	4. DRAIN	CATHODE	4. COLLECTOR	4. ANODE	4. CATHODE

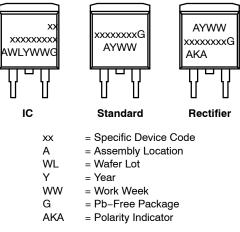
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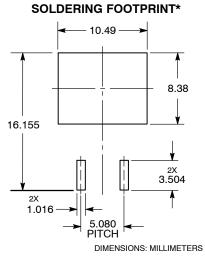
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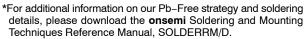
DATE 17 FEB 2015

GENERIC MARKING DIAGRAM*



*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.





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